

# GaAs INTEGRATED CIRCUIT $\mu$ PG2115TB

## L-BAND PA DRIVER AMPLIFIER

#### DESCRIPTION

The  $\mu$ PG2115TB is a GaAs MMIC for PA driver amplifiers developed for L-band mobile communication applications.

This device realizes low voltage operation with low current and low distortion characteristics. Moreover, the device has HPF-type input matching circuit built-in, external parts are only three.

The package employed is a 6-pin super minimold.

#### FEATURES

- Low operation voltage: VDD = 3.0 V
- f: 893 to 960 MHz @ Pout = +8 dBm
- Low distortion: P<sub>adj1</sub> = -60 dBc TYP. @ V<sub>DD</sub> = 3.0 V, P<sub>out</sub> = +8 dBm External output matching
- Low operation current: IDD = 12 mA TYP. @ VDD = 3.0 V, Pout = +8 dBm External output matching
- 6-pin super minimold package

#### APPLICATION

• Digital cellular: PDC800MHz etc.

#### ORDERING INFORMATION

| Part Number  | Package              | Marking | Supplying Form                        |
|--------------|----------------------|---------|---------------------------------------|
| μPG2115TB-E3 | 6-pin super minimold | G2C     | Embossed tape 8 mm wide.              |
|              |                      |         | Pin 1 face the tape perforation side. |
|              |                      |         | Qty 3kpcs / reel.                     |

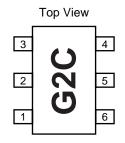
**Remark** To order evaluation samples, please contact your local NEC sales office. (Part number for sample order:  $\mu$ PG2115TB)

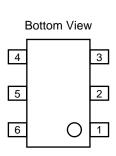
# Caution The IC must be handled with care to prevent static discharge because its circuit composed of GaAs HJ-FET.

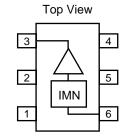
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#### **PIN CONNECTIONS**

| Pin No. | Connection     | Pin No. | Connection     |
|---------|----------------|---------|----------------|
| 1       | Non connection | 4       | Non connection |
| 2       | GND            | 5       | GND            |
| 3       | VDD & OUT      | 6       | IN             |







Remark IMN: Input Matching Network

#### ABSOLUTE MAXIMUM RATINGS (TA = +25°C)

| Parameter                     | Symbol | Ratings             | Unit |
|-------------------------------|--------|---------------------|------|
| Supply Voltage                | Vdd    | 6.0                 | V    |
| Input Power                   | Pin    | 0                   | dBm  |
| Total Power Dissipation       | Ptot   | 140 <sup>Note</sup> | mW   |
| Operating Ambient Temperature | TA     | -30 to +90          | °C   |
| Storage Temperature           | Tstg   | -35 to +150         | °C   |

**Note** Mounted on a  $50 \times 50 \times 1.6$  mm double copper clad epoxy glass PWB, T<sub>A</sub> = +85°C

**RECOMMENDED OPERATING CONDITIONS (TA = +25°C)** 

| Parameter      | Symbol | MIN. | TYP. | MAX. | Unit |
|----------------|--------|------|------|------|------|
| Supply Voltage | VDD    | +2.7 | +3.0 | +3.3 | V    |
| Input Power    | Pin    | -    | -9   | -6   | dBm  |

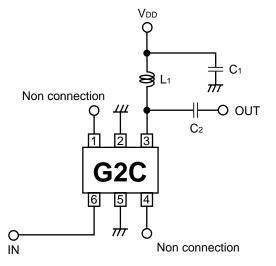
#### **ELECTRICAL CHARACTERISTICS**

(Unless otherwise specified, T<sub>A</sub> = +25°C, V<sub>DD</sub> = +3.0 V,  $\pi$ /4DQPSK modulated signal input, external output matching)

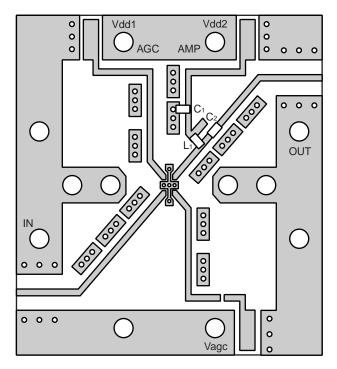
| Parameter                        | Symbol | Test Conditions   | MIN. | TYP. | MAX. | Unit |
|----------------------------------|--------|---|------|------|------|------|
| Operating Frequency              | f      |   | 893  | -    | 960  | MHz  |
| Power Gain                       | Gp     | P <sub>out</sub> = +8 dBm   | 14   | 17   | 20   | dB   |
| Total Current                    | IDD    | P <sub>out</sub> = +8 dBm   | -    | 12   | 16   | mA   |
| Adjacent Channel Power Leakage 1 | Padj1  | $P_{out} = +8 \text{ dBm}$<br>$\Delta f = \pm 50 \text{ kHz}$ , 21 kHz Band Width                 | -    | -60  | -55  | dBc  |
| Adjacent Channel Power Leakage 2 | Padj2  | $P_{out} = +8 \text{ dBm}$<br>$\Delta f = \pm 100 \text{ kHz}, 21 \text{ kHz} \text{ Band Width}$ | -    | -70  | -65  | dBc  |

#### **EVALUATION CIRCUIT**

 $V_{DD}$  = +3.0 V, f = 925 MHz

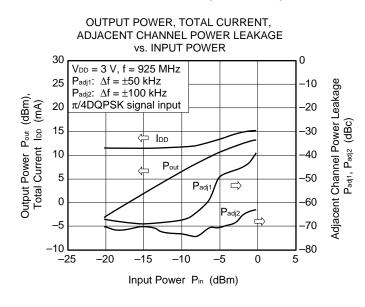


#### **EVALUATION BOARD**



#### USING THE NEC EVALUATION BOARD

| Symbol | Values   | Part Number     | Maker  |
|--------|----------|-----------------|--------|
| C1     | 1 000 pF | GRM39CH 102 K50 | muRata |
| C2     | 1.8 pF   | GRM39CK 1R8 C50 | muRata |
| L1     | 10 nH    | TFL0816 10N     | susumu |

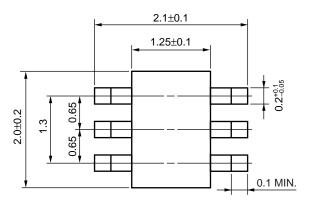


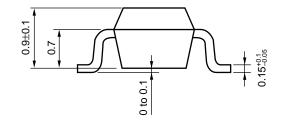
TYPICAL CHARACTERISTICS (TA = +25°C)

Remark The graph indicates nominal characteristics.

#### PACKAGE DIMENSIONS

### 6-PIN SUPER MINIMOLD (UNIT: mm)





#### **RECOMMENDED SOLDERING CONDITIONS**

This product should be soldered under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your NEC sales representative.

| Soldering Method | Soldering Conditions  | Recommended Condition Symbol |
|------------------|---|------------------------------|
| Infrared Reflow  | Package peak temperature: 235°C or below<br>Time: 30 seconds or less (at 210°C)<br>Count: 3, Exposure limit: None <sup>Note</sup> | IR35-00-3                    |
| VPS              | Package peak temperature: 215°C or below<br>Time: 40 seconds or less (at 200°C)<br>Count: 3, Exposure limit: None <sup>Note</sup> | VP15-00-3                    |
| Wave Soldering   | Soldering bath temperature: 260°C or below<br>Time: 10 seconds or less<br>Count: 1, Exposure limit: None <sup>Note</sup>          | WS60-00-1                    |
| Partial Heating  | Pin temperature: 300°C<br>Time: 3 seconds or less (per side of device)<br>Exposure limit: None <sup>Note</sup>                    | _                            |

Note After opening the dry pack, keep it in a place below 25°C and 65% RH for the allowable storage period.

#### Caution Do not use different soldering methods together (except for partial heating).

For details of recommended soldering conditions for surface mounting, refer to information document SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL (C10535E).

#### CAUTION

The great care must be taken in dealing with the devices in this guide. The reason is that the material of the devices is GaAs (Gallium Arsenide), which is designated as harmful substance according to the law concerned. Keep the law concerned and so on, especially in case of removal.

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